## NSN 5961-01-095-1439

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View Online at https://aerobasegroup.com/nsn/5961-01-095-1439 **Inclosure Material:** Metal **Overall Length:** 0.460 inches **Overall Diameter:** 0.610 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-emitter, base open and 150.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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